

# RN2967FE(TE85L,F)

## **RN2967FE**(TE85L,F) Information

Numericon	RN2967FE(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2PNP PREBIAS 0.1W ES6 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# **RN2967FE**(TE85L,F) Specifications

Manufacturer Part Number	RN2967FE(TE85L,F)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Package	SOT-563, SOT-666
Series	-
Transistor Type	2 PNP - Pre-Biased (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	10k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	200MHz
Power - Max	100mW
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	ES6
	Report errors?

### RN2967FE(TE85L,F) Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### **RN2967FE**(TE85L,F) Payment Methods





If you have any question about RN2967FE(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com